

1SS367

SILICON EPITAXIAL SCHOTTKY BARRIER DIODE

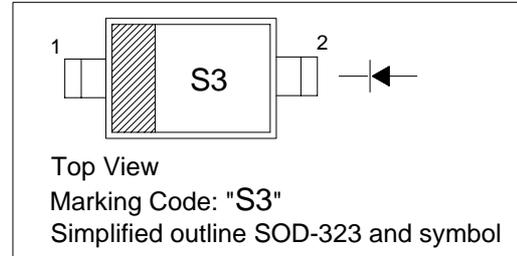
High Speed Switching Applicatio

Features

- Low forward voltage:
 $V_F = 0.23V$ (typ.) @ $I_F = 5mA$

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode

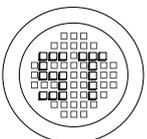


Absolute Maximum Ratings (T_j = 25 ?)

Parameter	Symbol	Value	Unit
Maximum (peak) Reverse Voltage	V_{RM}	15	V
Reverse Voltage	V_R	10	V
Maximum (peak) Forward Current	I_{FM}	200	mA
Average Forward Current	I_O	100	mA
Surge Current (10ms)	I_{FSM}	1	A
Power Dissipation	P_{tot}	200	mW
Junction Temperature	T_J	125	?
Storage Temperature Range	T_s	-55 to +125	?
Operating Temperature Range	T_{opr}	-40 to +100	?

Characteristics at T_j = 25 ?

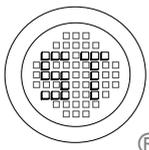
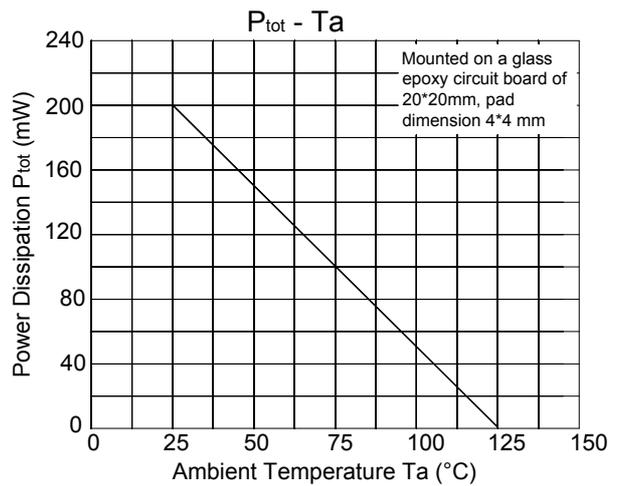
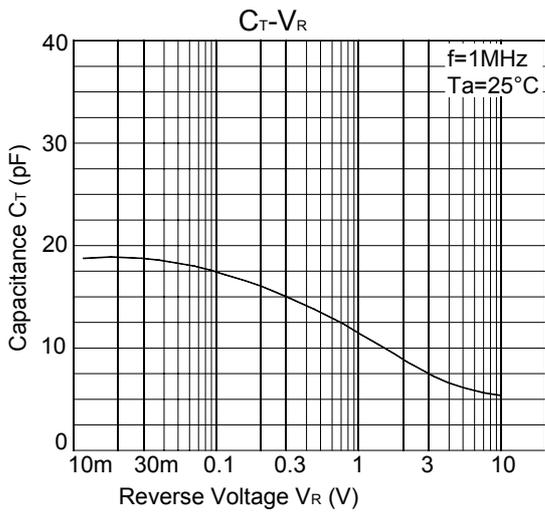
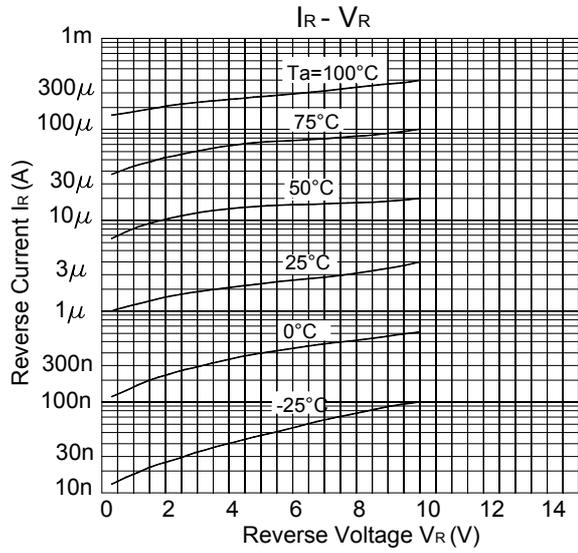
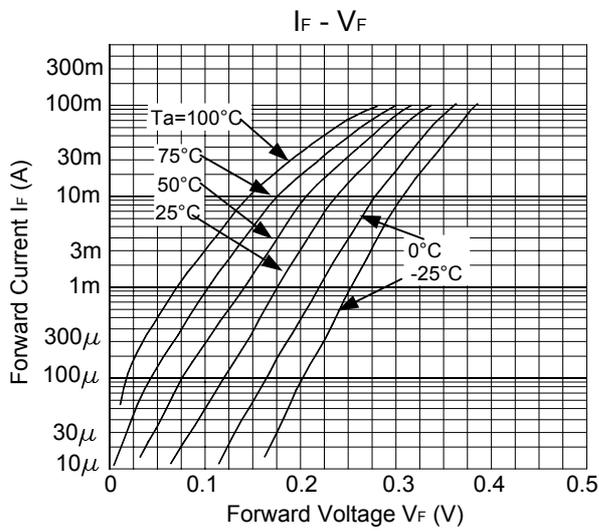
Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
Forward Voltage	$I_F = 1mA$	V_F	-	0.18	-	V
	$I_F = 5mA$	V_F	-	0.23	0.30	V
	$I_F = 100mA$	V_F	-	0.35	0.50	V
Reverse Current	$V_R = 10V$	I_R	-	-	20	μA
Total Capacitance	$f = 1MHz$	C_T	-	20	40	μF



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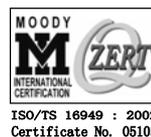
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SEMTECH ELECTRONICS LTD.

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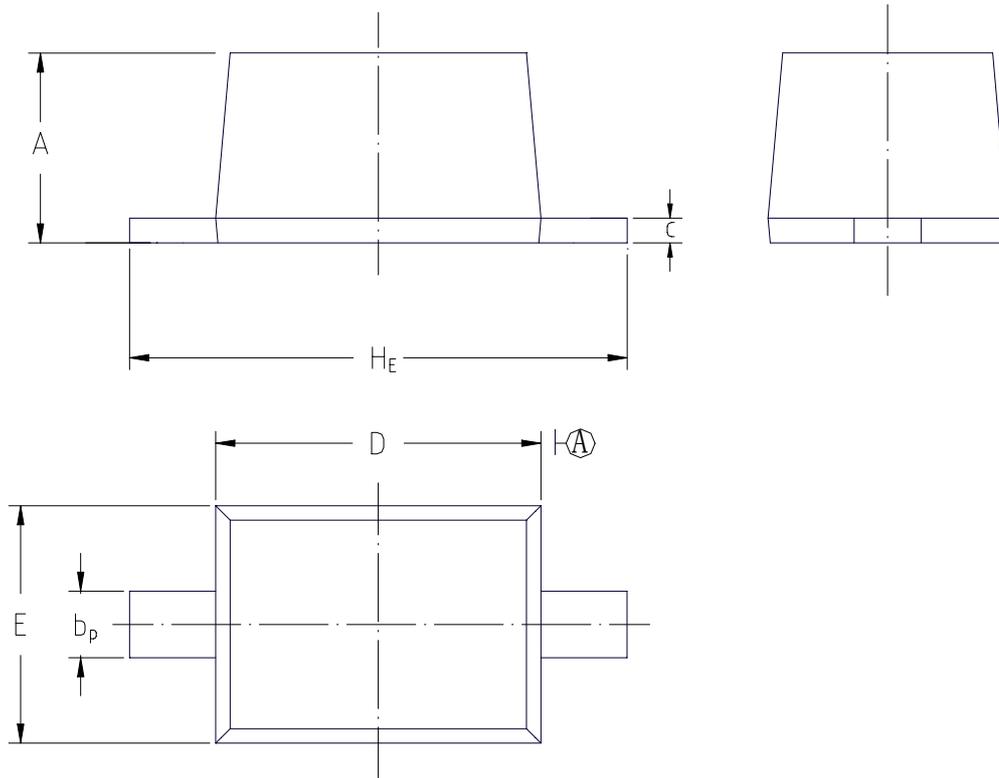


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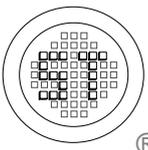
PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



UNIT	A	b_p	c	D	E	H_E
mm	1.10 0.80	0.40 0.25	0.15 0.00	1.80 1.60	1.35 1.15	2.80 2.30



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ISO/TS 16949 : 2002
Certificate No. 05103



ISO 14001
Certificate No. 7116



ISO 9001 : 2000
Certificate No. 550-1559-04-002-04

Dated : 30/08/2004